

CLC1005, CLC1015, CLC2005

Low Cost, +2.7V to 5.5V, 260MHz Rail-to-Rail Amplifiers

General Description

The CLC1005 (single), CLC1015 (single with disable), and CLC2005 (dual) are low cost, voltage feedback amplifiers. These amplifiers are designed to operate on +2.7V to +5V, or ±2.5V supplies. The input voltage range extends 300mV below the negative rail and 1.2V below the positive rail.

The CLC1005, CLC1015, and CLC2005 offer superior dynamic performance with 260MHz small signal bandwidth and 145V/ μ s slew rate. The amplifiers consume only 4.2mA of supply current per channel and the CLC1015 offers a disable supply current of only 127 μ A. The combination of low power, high output current drive, and rail-to-rail performance make these amplifiers well suited for battery-powered communication/computing systems.

The combination of low cost and high performance make the CLC1005, CLC1015, and CLC2005 suitable for high volume applications in both consumer and industrial applications such as interactive whiteboards, wireless phones, scanners, color copiers, and video transmission.

FEATURES

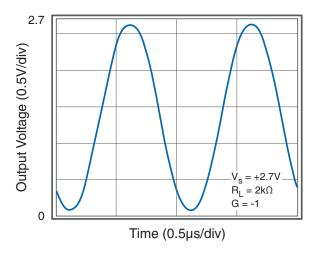
- 260MHz bandwidth
- Fully specified at +2.7V and +5V supplies
- Output voltage range:
 - \circ 0.036V to 4.953V; $V_S = +5$; $R_L = 2k\Omega$
- Input voltage range:
 - -0.3V to +3.8V; $V_S = +5$
- 145V/µs slew rate
- 4.2mA supply current
- Power down to 127µA
- ±55mA linear output current
- ±85mA short circuit current
- CLC2005 directly replaces AD8052/42/92 in single supply applications
- CLC1005 directly replaces AD8051/41/91 in single supply applications

APPLICATIONS

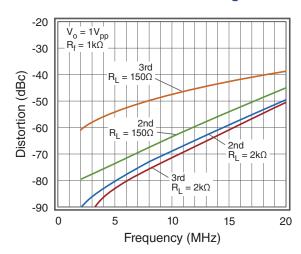
- A/D driver
- Active filters
- CCD imaging systems
- CD/DVD ROM
- Coaxial cable drivers
- High capacitive load driver
- Portable/battery-powered applications
- Twisted pair driver
- Telecom and optical terminals
- Video driver
- Interactive whiteboards

Ordering Information - backpage

Output Swing



2nd & 3rd Harmonic Distortion; $V_S = +2.7V$



Absolute Maximum Ratings

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

V _S	0V to +6V
V _{IN} V _S - 0.5V to	+V _S +0.5V

Operating Conditions

Supply Voltage Range	2.5 to 5.5V
Operating Temperature Range	40°C to 85°C
Junction Temperature	150°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering, 10s)	260°C

Package Thermal Resistance

θ _{JA} (SOIC-8)			150°C/W
θ _{JA} (MSOP-8)			200°C/W
θ _{JA} (TSOT23-5)			215°C/W
θ _{JA} (TSOT23-6)			192°C/W
Package thermal resistance (A _{1A})	JEDEC	standard	multi-laver

Package thermal resistance (θ_{JA}), JEDEC standard, multi-layer test boards, still air.

ESD Protection

SOIC-8 (HBM)2.5k	۲V
ESD Rating for HBM (Human Body Model) and CDM (Charge Device Model).	èd

Electrical Characteristics at +2.7V

 T_A = 25°C, V_S = +2.7V, R_f = 2k Ω , R_L = 2k Ω to $V_S/2;$ G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency I	Domain Response					
GBWP	-3dB Gain Bandwidth Product			86		MHz
UGBW	Unity Gain Bandwidth(1)	$G = +1, V_{OUT} = 0.05V_{pp}$		215		MHz
BW _{SS}	-3dB Bandwidth	$G = +2, V_{OUT} = 0.2V_{pp}$		85		MHz
BW _{LS}	Large Signal Bandwidth	$G = +2$, $V_{OUT} = 2V_{pp}$		36		MHz
Time Doma	in		'	'		·
t _R , t _F	Rise and Fall Time (1)	V _{OUT} = 0.2V step; (10% to 90%)		3.7		ns
t _S	Settling Time to 0.1%	V _{OUT} = 1V step		40		ns
OS	Overshoot	V _{OUT} = 0.2V step		9		%
SR	Slew Rate	G = -1, 2.7V step		130		V/µs
Distortion/N	oise Response		<u> </u>			
HD2	2nd Harmonic Distortion (1)	5MHz, V _{OUT} = 1V _{pp}		79		dBc
HD3	3rd Harmonic Distortion (1)	$5MHz$, $V_{OUT} = 1V_{pp}$		82		dBc
THD	Total Harmonic Distortion (1)	5MHz, V _{OUT} = 1V _{pp}		77		dB
e _n	Input Voltage Noise	>1MHz		16		nV/√Hz
i _n	Input Current Noise	>1MHz		1.3		pA/√Hz
X _{TALK}	Crosstalk ⁽¹⁾	CLC2005, 10MHz		65		dB
DC Perform	ance					
V _{IO}	Input Offset Voltage			-1.6		mV
d _{VIO}	Average Drift			10		μV/°C
I _B	Input Bias Current			3		μΑ
dl _B	Average Drift			7		nA/°C
I _{OS}	Input Offset Current			0.1		μΑ
PSRR	Power Supply Rejection Ratio	DC	52	57		dB
A _{OL}	Open Loop Gain			75		dB
I _S	Supply Current			3.9		mA
Disable Characteristics (CLC1015)						
T _{ON}	Turn On Time			150		ns
T _{OFF}	Turn Off Time			25		ns
OFFISO	Off Isolation	5MHz, $R_L = 100\Omega$		75		dB
I _{SD}	Disable Supply Current	DIS tied to GND		58	100	μA
Input Chara	1 1 1	DIO IIOG IO GIAD		00	100	μ/τ
R _{IN}	Input Resistance			4.3		ΜΩ
C _{IN}	Input Capacitance			1.8		pF
CMIR	Common Mode Input Range			-0.3 to 1.5		V
CMRR	Common Mode Rejection Ratio	DC, V _{CM} = 0 to V _S - 1.5V		87		dB
Output Characteristics Output Characteristics						
Output Offa	Tactoristics			0.023 to		
		$R_L = 10k\Omega$ to $V_S/2$		2.66		V
V_{OUT}	Output Swing	$R_L = 2k\Omega$ to $V_S/2$		0.025 to		V
				2.653 0.065 to		
		$R_L = 150\Omega$ to $V_S/2$		2.55		V
I _{OUT}	Output Current			±55		mA
.001	·	-40°C to +85°C		±50		mA
I _{SC}	Short Circuit Current	$V_{OUT} = V_S / 2$		±85		mA
Vs	Power Supply Operating Range		2.5	2.7	5.5	V

Notes

^{1.} $R_f=1k\Omega$ was used for optimal performance. (For $G=+1,\ R_f=0)$

Electrical Characteristics at +5V

 T_A = 25°C, V_S = +5V, R_f = 2k Ω , R_L = 2k Ω to $V_S/2;$ G = 2; unless otherwise noted.

Frequency Demain Response GBWP -3dB Gain Bandwidth Product 90 MHz LGGWW July Gain Bandwidth Product G = +1, V _{DUT} = 0.05V _{pp} 260 MHz BWs -3dB Bandwidth G = +2, V _{DUT} = 0.2V _{pp} 90 MHz BWs Large Signal Bandwidth G = +2, V _{DUT} = 2V _{pp} 40 MHz BWs Large Signal Bandwidth G = +2, V _{DUT} = 2V _{pp} 40 MHz BWs Large Signal Bandwidth V _{DUT} = 0.2V step 3.6 ns Immediate V _{DUT} = 0.2V step 40 ns SS Settling Time to 0.1% V _{DUT} = 0.2V step 40 ns SR Settling Time to 0.1% V _{DUT} = 0.2V step 7 % SR Silver Rate G = -1, 5V step 7 % SR Silver Rate G = -1, 5V step 71 MBc BLD 2nd Harmonic Distortion (**) SMHz, V _{DUT} = 2V _{pp} 71 1 dBc BLD 2nd Harmonic Distortion (**) SMHz, V _{DUT} = 2V _{pp} 7 7 dBc	Symbol	Parameter	Conditions	Min	Тур	Max	Units
UGBW Unity Gain Bandwidth ^(γ) G = +1, V _{OUT} = 0.05V _{pp} 260 MHz BW _{SS} -3dB Bandwidth G = +2, V _{OUT} = 0.2V _{pp} 90 MHz BW _{SS} -3dB Bandwidth G = +2, V _{OUT} = 2V _{pp} 90 MHz BW _{SS} -3dB Bandwidth G = +2, V _{OUT} = 2V _{pp} 40 MHz Time Domain T 40 MHz Time Domain Wout = 0.2V step 3.6 Ins Is Settling Time to 0.1% V _{OUT} = 0.2V step 7 % OS Overshoot V _{OUT} = 0.2V step 7 % SR Slew Rate G = -1, 5V step 145 V/µs Distortion/Nose BMEX V _{OUT} = 2V _{Pp} 70 4B HD2 2nd Harmonic Distortion (II) SMHz, V _{OUT} = 2V _{Pp} 78 4Be HD3 3rd Harmonic Distortion (III) SMHz, V _{OUT} = 2V _{Pp} 70 4B HD2 2nd Harmonic Distortion (III) SMHz, V _{OUT} = 2V _{Pp} 70 4B HD2 2nd Harmonic Distortion (III) <td< td=""><td>Frequency [</td><td>Domain Response</td><td></td><td></td><td></td><td></td><td></td></td<>	Frequency [Domain Response					
BWSS -3dB Bandwidth G = +2, V _{OUT} = 0.2V _{PP} 90 4d MHz BWSS Large Signal Bandwidth G = +2, V _{OUT} = 2V _{PP} 4d MHz Time Domain	GBWP	-3dB Gain Bandwidth Product			90		MHz
BWLs	UGBW	Unity Gain Bandwidth(1)	$G = +1, V_{OUT} = 0.05V_{pp}$		260		MHz
Time Domain Use Rise and Fall Time O	BW _{SS}	-3dB Bandwidth	$G = +2, V_{OUT} = 0.2V_{pp}$		90		MHz
I _R , I _F Rise and Fall Time (°) V _{OUT} = 0.2V step 3.6 ns t _S Settling Time to 0.1% V _{OUT} = 0.2V step 40 ns OS Overshoot V _{OUT} = 0.2V step 7 % SR Silew Rate G = -1, 5V step 145 V/µs Dispersion (Notice Propose) HD2 2nd Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 71 dBc HD3 3rd Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 70 dBc THD Total Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 70 dBc THD Total Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 70 dB THD Total Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 70 dB DB Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % THD Total Harmonic Distortion (°) NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.06 % DP Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % <	BW _{LS}	Large Signal Bandwidth	$G = +2$, $V_{OUT} = 2V_{pp}$		40		MHz
tg Settling Time to 0.1% V _{OUT} = 2V step 40 ns OS Overshoot V _{OUT} = 0.2V step 7 % SR Slew Rate G = -1, 5V step 145 V/μs SIGN Rate G = -1, 5V step 145 V/μs Distortion/Noise Response HD2 2nd Harmonic Distortion (0) 5MHz, V _{OUT} = 2V _{pp} 71 dBc HD3 3rd Harmonic Distortion (0) 5MHz, V _{OUT} = 2V _{pp} 78 dBc THD Total Harmonic Distortion (0) 5MHz, V _{OUT} = 2V _{pp} 70 dBc THD Total Harmonic Distortion (0) 5MHz, V _{OUT} = 2V _{pp} 70 0.06 DB Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 1500 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 1500 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 1500 0.06 0.07 % en Input Voltage Noise >1MHz 16 n.V/Hz M n. n. n. n. n. n. n.	Time Doma	in		•	,		
OS Overshoot VOUT = 0.2V step 7 % SR Slew Rate G = -1, 5V step 145 V/μs Distortion/Noise Response HD2 2nd Harmonic Distortion (**) 5MHz, Vour = 2Vpp 78 dBc HD3 3rd Harmonic Distortion (**) 5MHz, Vour = 2Vpp 78 dBc HD0 Total Harmonic Distortion (**) 5MHz, Vour = 2Vpp 70 dB DB Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.08 % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 ° en Input Voltage Noise >1MHz 1.3 pAVHz XTALK Crosstalk(**) CC2005, 10MHz 1.3 pAVHz DC Performance *** *** *** *** VIO Input Offset Voltage *** *** *** *** VIO Input Offset Voltage *** ***	t _R , t _F	Rise and Fall Time (1)	V _{OUT} = 0.2V step		3.6		ns
SR Slew Rate G = -1, 5V step 145 V/μs Distortion/No/ise Response HD2 2nd Harmonic Distortion (°) 5MHz, Vouт = 2Vpp 71 dBc HD3 3rd Harmonic Distortion (°) 5MHz, Vouт = 2Vpp 70 dB THD Total Harmonic Distortion (°) 5MHz, Vouт = 2Vpp 70 dB THD Total Harmonic Distortion (°) 5MHz, Vour = 2Vpp 70 dB DG Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.08 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω	t _S	Settling Time to 0.1%	V _{OUT} = 2V step		40		ns
Distortion/Noise Response HD2 2nd Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 71 dBc HD3 3rd Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 78 dBc THD Total Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 70 dBc THD Total Harmonic Distortion (°) 5MHz, V _{OUT} = 2V _{pp} 70 0.06 % DB Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.08 % % % % en Input Voltage Noise >1MHz 16 n/V/Hz in/V/Hz in/V/	OS	Overshoot	V _{OUT} = 0.2V step		7		%
HD2	SR	Slew Rate	G = -1, 5V step		145		V/µs
HD3	Distortion/N	oise Response		'	,		<u>'</u>
HD3	HD2	2nd Harmonic Distortion (1)	5MHz, V _{OUT} = 2V _{pp}		71		dBc
DG Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.08 % % NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.07 0.08 % % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.07 0.0	HD3	3rd Harmonic Distortion (1)			78		dBc
DG Differential Gain NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.06 % DP Differential Phase NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.07 ° e _n Input Voltage Noise >1MHz 16 nV/yHz i _n Input Current Noise >1MHz 13 pA/yHz X _{TALK} Crosstalk ⁽¹⁾ CLC2005, 10MHz 13 pA/yHz X _{TALK} Crosstalk ⁽²⁾ CLC2005, 10MHz 62 dB DC Performmer VIO Input Offset Voltage 8 1.4 8 mV d _{VIO} Average Drift 9 8 1.4 8 mV d _{IB} Input Bias Current 9 8 1.4 8 mV l _{IB} Input Gffset Current 9 8 1.4 8 μA A _{OL} Open Loop Gain DC 52 57 dB A _{OL} Open Loop Gain 68 78 dB I _S Supply Current	THD	Total Harmonic Distortion (1)	5MHz, V _{OUT} = 2V _{pp}		70		dB
NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.08 % NTSC (3.85MHz), AC-Coupled, R _L = 150Ω 0.07 0.07 0.08 0.08 0.09 0			 ''		0.06		%
DP Differential Phase NTSC (3.85MHz), DC-Coupled, R _L = 150Ω 0.06 ° en Input Voltage Noise >1MHz 16 nVI/Hz in Input Current Noise >1MHz 1.3 pA/yHz X _{TALK} Crosstalk ⁽⁴⁾ CLC2005, 10MHz 62 dB DC Performs VIC Input Offset Voltage -8 1.4 8 mV V _{IO} Average Drift -9 -8 1.4 8 mV d _{ID} Average Drift -9 -8 1.4 8 mV d _{IB} Input Bias Current -9 -8 3 8 μA d _{IB} Input Offset Current -9 -8 3 8 μA PSRR Power Supply Rejection Ratio DC -9.8 0.1 0.8 μA A _{OL} Open Loop Gain DC 52 57 dB I _S Supply Current -9 4.2 5.2 mA D _{IS} able Charteristics (CL	DG	Differential Gain	NTSC (3.85MHz), DC-Coupled, $R_L = 150\Omega$		0.08		%
en Input Voltage Noise >1MHz 16 n NV/yHz in Input Current Noise >1MHz 13 p AV/yHz X _{TALK} Cosstalk(¹) CLC2005, 10MHz 62 dB DC Performace VIO Input Offset Voltage -8 1.4 8 mV d _{VIO} Average Drift -8 1.4 8 mV d _{IB} Input Bias Current -8 3 8 μA d _{IB} Average Drift -8 3 8 μA d _{IB} Input Offset Current -8 3 8 μA I _{OS} Input Offset Current -0.8 0.1 0.8 μA PSRR Power Supply Rejection Ratio DC 52 57 dB I _S Supply Current			NTSC (3.85MHz), AC-Coupled, $R_L = 150\Omega$		0.07		0
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	DP	Differential Phase	NTSC (3.85MHz), DC-Coupled, $R_L = 150\Omega$		0.06		0
In Input Current Noise >1MHz 1.3 pAV/Hz X_{TALK} Crosstalk(1) CLC2005, 10MHz 62 dB DC Performs. VIO Input Offset Voltage -8 1.4 8 mV d_{VIO} Average Drift 10 μV/°C μV/°C 10 10 μV/°C 10 10 μV/°C 10 10 μV/°C 10 10 10 μV/°C 10 10 10 10 10 10 10 10 10 10 10 10 10 10 10 10 10	e _n	Input Voltage Noise	>1MHz		16		nV/√Hz
DC Performance V _{IO} Input Offset Voltage -8 1.4 8 mV d _{VIO} Average Drift 10 μV/°C I _B Input Bias Current -8 3 8 μA dI _B Average Drift 7 nA/°C		Input Current Noise	>1MHz		1.3		pA/√Hz
DC Performance V _{IO} Input Offset Voltage -8 1.4 8 mV d _{VIO} Average Drift 10 μV/°C I _B Input Bias Current -8 3 8 μA dI _B Average Drift 7 nA/°C	X _{TALK}	Crosstalk ⁽¹⁾	CLC2005, 10MHz		62		dB
dyIO Average Drift 10 μV/°C I _B Input Bias Current -8 3 8 μA dI _B Average Drift 7 nA/°C nA/°C I _{OS} Input Offset Current -0.8 0.1 0.8 μA PSRR Power Supply Rejection Ratio DC 52 57 dB A _{OL} Open Loop Gain 68 78 dB I _S Supply Current 4.2 5.2 mA Disable Charcteristics (CLC1015) Turn On Time 150 ns T _{OFF} Turn Off Time 25 ns OFF I _{SO} Off Isolation 5MHz, R _L = 100Ω 75 dB I _{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Charcteristics R _{IN} Input Resistance 4.3 MΩ							<u>'</u>
dyIO Average Drift 10 μV/°C I _B Input Bias Current -8 3 8 μA dI _B Average Drift 7 nA/°C nA/°C I _{OS} Input Offset Current -0.8 0.1 0.8 μA PSRR Power Supply Rejection Ratio DC 52 57 dB A _{OL} Open Loop Gain 68 78 dB I _S Supply Current 4.2 5.2 mA Disable Charcteristics (CLC1015) Turn On Time 150 ns T _{OFF} Turn Off Time 25 ns OFF I _{SO} Off Isolation 5MHz, R _L = 100Ω 75 dB I _{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Charcteristics R _{IN} Input Resistance 4.3 MΩ	V _{IO}	Input Offset Voltage		-8	1.4	8	mV
IB Input Bias Current -8 3 8 μA dIB Average Drift 7 nA/°C IOS Input Offset Current -0.8 0.1 0.8 μA PSRR Power Supply Rejection Ratio DC 52 57 dB A _{OL} Open Loop Gain 68 78 dB I _S Supply Current 4.2 5.2 mA Disable Characteristics (CLC1015) Turn On Time 150 ns T _{OFF} Turn Off Time 25 ns OFF _{ISO} Off Isolation 5MHz, R _L = 100Ω 75 dB I _{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R _{IN} Input Resistance 4.3 MΩ		Average Drift			10		μV/°C
dIBAverage Drift7 $nA/^{o}C$ I_{OS} Input Offset Current-0.80.10.8 μA PSRRPower Supply Rejection RatioDC5257dB A_{OL} Open Loop Gain6878dB I_{S} Supply Current4.25.2 mA Disable Characteristics (CLC1015) T_{ON} Turn On Time150 ns T_{OFF} Turn Off Time25 ns OFF_{ISO} Off Isolation $5MHz$, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current \overline{DIS} tied to GND127170 μA Input Characteristics R_{IN} Input Resistance4.3 $M\Omega$		Input Bias Current		-8	3	8	μΑ
PSRRPower Supply Rejection RatioDC5257dB A_{OL} Open Loop Gain6878dB I_S Supply Current4.25.2mADisable Characteristics (CLC1015) T_{ON} Turn On Time150ns T_{OFF} Turn Off Time25nsOFF I_{SO} Off Isolation5MHz, $R_L = 100\Omega$ 75dB I_{SD} Disable Supply Current \overline{DIS} tied to GND127170 μ AInput Characteristics R_{IN} Input Resistance4.3 $M\Omega$		Average Drift			7		nA/°C
PSRRPower Supply Rejection RatioDC5257dB A_{OL} Open Loop Gain6878dB I_S Supply Current4.25.2mADisable Characteristics (CLC1015) T_{ON} Turn On Time150ns T_{OFF} Turn Off Time25ns OFF_{ISO} Off Isolation5MHz, $R_L = 100\Omega$ 75dB I_{SD} Disable Supply Current \overline{DIS} tied to GND127170 μ AInput Characteristics R_{IN} Input Resistance4.3 $M\Omega$	I _{OS}	Input Offset Current		-0.8	0.1	0.8	μΑ
Is Supply Current 4.2 5.2 mA Disable Characteristics (CLC1015) T_{ON} Turn On Time 150 ns T_{OFF} Turn Off Time 25 ns OFF _{ISO} Off Isolation 5MHz, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R_{IN} Input Resistance 4.3 MΩ		Power Supply Rejection Ratio	DC	52	57		dB
Is Supply Current 4.2 5.2 mA Disable Characteristics (CLC1015) T_{ON} Turn On Time 150 ns T_{OFF} Turn Off Time 25 ns OFF IsO Off Isolation 5MHz, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R_{IN} Input Resistance 4.3 MΩ	A _{OL}	Open Loop Gain		68	78		dB
T_{ON} Turn On Time 150 ns T_{OFF} Turn Off Time 25 ns OFF _{ISO} Off Isolation 5MHz, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R_{IN} Input Resistance 4.3 MΩ		Supply Current			4.2	5.2	mA
T_{OFF} Turn Off Time 25 ns OFF _{ISO} Off Isolation 5MHz, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R_{IN} Input Resistance 4.3 MΩ	Disable Cha	aracteristics (CLC1015)					
T_{OFF} Turn Off Time 25 ns OFF _{ISO} Off Isolation 5MHz, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R_{IN} Input Resistance 4.3 MΩ					150		ns
OFF ISO Off Isolation 5MHz, $R_L = 100\Omega$ 75 dB I_{SD} Disable Supply Current DIS tied to GND 127 170 μA Input Characteristics R_{IN} Input Resistance 4.3 $MΩ$		Turn Off Time			25		ns
I _{SD} Disable Supply Current \overline{DIS} tied to GND 127 170 μA Input Characteristics R _{IN} Input Resistance 4.3 $MΩ$			5MHz, $R_L = 100\Omega$		-		dB
$\begin{tabular}{ll} Input Characteristics & & & & & & & & & & & & & & & & & & &$		Disable Supply Current	DIS tied to GND		127	170	μΑ
R _{IN} Input Resistance 4.3 MΩ	95						· ·
	•				4.3		ΜΩ
		· ·			1.8		pF
CMIR Common Mode Input Range -0.3 to 3.8 V					-0.3 to		
CMRR Common Mode Rejection Ratio DC, V _{CM} = 0 to V _S - 1.5V 72 87 dB	CMRR	Common Mode Rejection Ratio	DC, V _{CM} = 0 to V _S - 1.5V	72			dB

Electrical Characteristics at +5V Continued

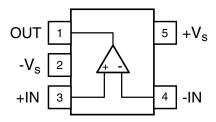
 T_A = 25°C, V_S = +5V, R_f = 2k Ω , R_L = 2k Ω to $V_S/2;$ G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units		
Output Chai	Output Characteristics							
		$R_L = 10k\Omega$ to $V_S/2$		0.027 to 4.97		V		
V _{OUT} Out	Output Swing	$R_L = 2k\Omega$ to $V_S/2$		0.036 to 4.953		V		
		$R_L = 150\Omega$ to $V_S/2$	0.3	0.12 to 4.8	4.625	V		
	Output Current			±55		mA		
IOUT	Output Current	-40°C to +85°C		±50		mA		
I _{SC}	Short Circuit Current	$V_{OUT} = V_S / 2$		±85		mA		
Vs	Power Supply Operating Range		2.5	5	5.5	V		

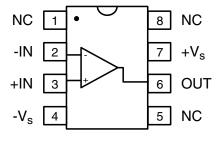
Notes:

^{1.} $R_f = 1k\Omega$ was used for optimal performance. (For G = +1, $R_f = 0$)

CLC1005 Pin ConfigurationsTSOT-5



SOIC-8



CLC1005 Pin Assignments

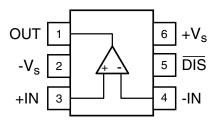
TSOT-5

Pin No.	Pin Name	Description
1	OUT	Output
2	-V _S	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	+V _S	Positive supply

SOIC-8

Pin No.	Pin Name	Description		
1	NC	No Connect		
2	-IN	Negative input		
3	+IN	Positive input		
4	-V _S	Negative supply		
5	NC	No Connect		
6	OUT	Output		
7	+V _S	Positive supply		
8	NC	No Connect		

CLC1015 Pin Configurations TSOT-6

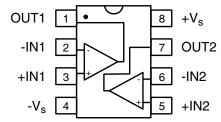


CLC1015 Pin Assignments

TSOT-6

Pin No.	Pin Name	Description		
1	OUT	Output		
2	-V _S	Negative supply		
3	+IN	Positive input		
4	-IN	Negative input		
5	DIS	Disable pin. Enabled if pin is left open or tied to +V _S , disabled if pin is tied to -V _S (which is GND in a single supply application.)		
6	+V _S	Positive supply		

CLC2005 Pin Configuration SOIC-8 / MSOP-8



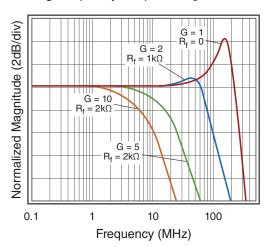
CLC2005 Pin Assignments

SOIC-8 / MSOP-8

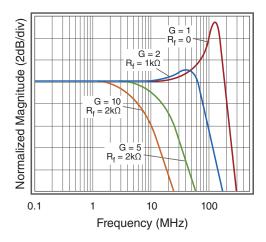
Pin No.	Pin Name	Description		
1	OUT1	Output, channel 1		
2	-IN1	Negative input, channel 1		
3	+IN1	Positive input, channel 1		
4	-V _S	Negative supply		
5	+IN2	Positive input, channel 2		
6	-IN2	Negative input, channel 2		
7	OUT2	Output, channel 2		
8	+V _S	Positive supply		

 $T_A = 25$ °C, $V_S = +5V$, $R_L = 2k\Omega$ to $V_S/2$, G = +2, $R_F = 2k\Omega$; unless otherwise noted.

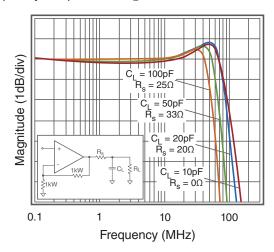
Non-Inverting Frequency Response $V_S = +5V$



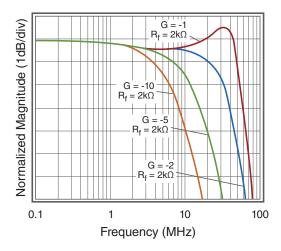
Non-Inverting Frequency Response $V_S = +2.7V$



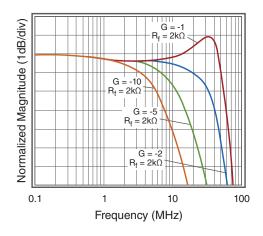
Frequency Response vs CL



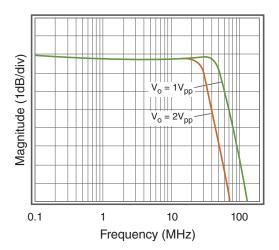
Inverting Frequency Response $V_S = +5V$



Inverting Frequency Response $V_S = +2.7V$

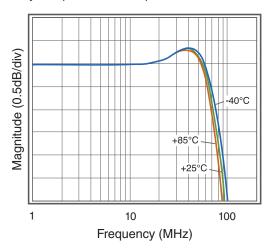


Large Signal Frequency Response

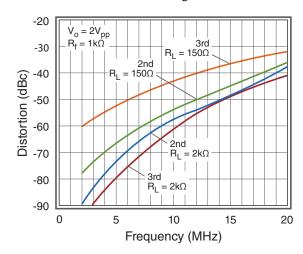


 $T_A = 25$ °C, $V_S = +5V$, $R_L = 2k\Omega$ to $V_S/2$, G = +2, $R_F = 2k\Omega$; unless otherwise noted.

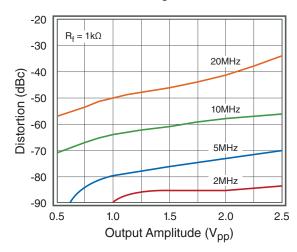
Frequency Response vs. Temperature



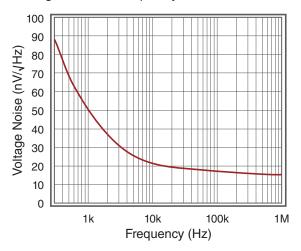
2nd & 3rd Harmonic Distortion $V_S = +5V$



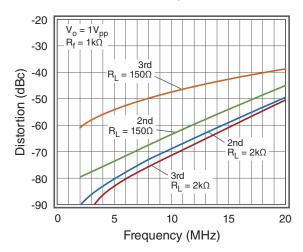
2nd Harmonic Distortion vs VO



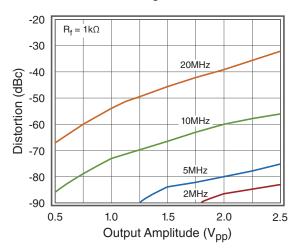
Input Voltage Noise vs Frequency



2nd & 3rd Harmonic Distortion $V_S = +2.7V$

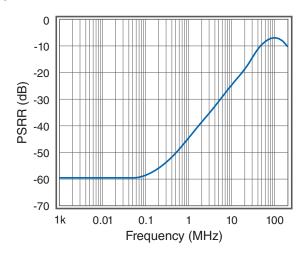


3rd Harmonic Distortion vs V_O

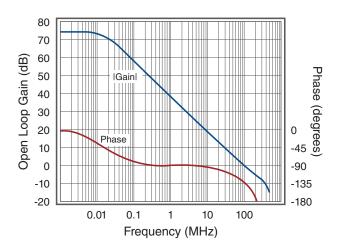


 $T_A = 25$ °C, $V_S = +5V$, $R_L = 2k\Omega$ to $V_S/2$, G = +2, $R_F = 2k\Omega$; unless otherwise noted.

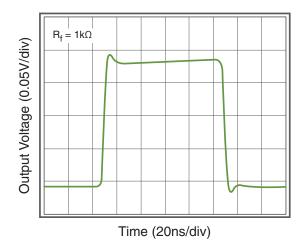
PSRR



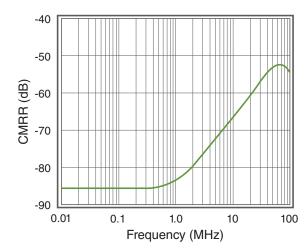
Open Loop Gain & Phase vs. Frequency



Small Signal Pulse Response V_S = +5V

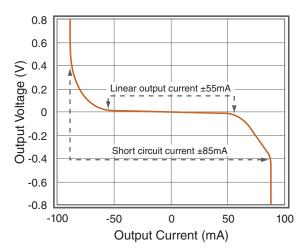


CMRR

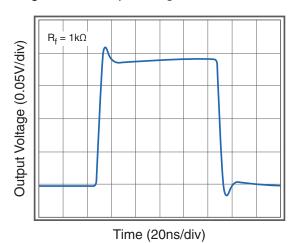


Output Current

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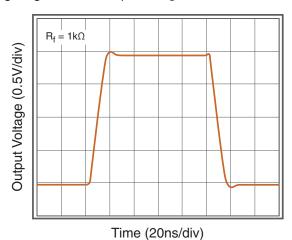


Small Signal Pulse Response V_S = +2.7V

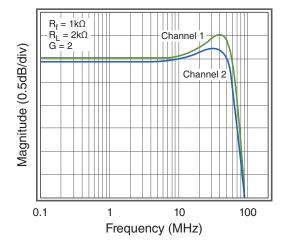


 $T_A = 25$ °C, $V_S = +5V$, $R_L = 2k\Omega$ to $V_S/2$, G = +2, $R_F = 2k\Omega$; unless otherwise noted.

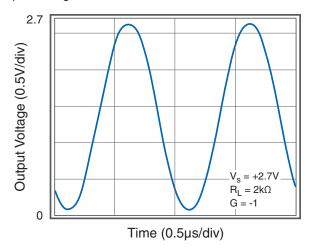
Large Signal Pulse Response $V_S = +5V$



Channel Matching $V_S = +5V$



Output Swing



Application Information

General Description

The CLC1005, CLC1015, and CLC2005 are single supply, general purpose, voltage-feedback amplifiers fabricated on a complementary bipolar process using a patented topography. They feature a rail-to-rail output stage and are unity gain stable. Both gain bandwidth and slew rate are insensitive to temperature.

The common mode input range extends to 300mV below ground and to 1.2V below V_s . Exceeding these values will not cause phase reversal. However, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices will begin to conduct. The output will stay at the rail during this overdrive condition.

The design is short circuit protected and offers "soft" saturation protection that improves recovery time.

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations. Figure 4 shows the typical non-inverting gain circuit for single supply applications.

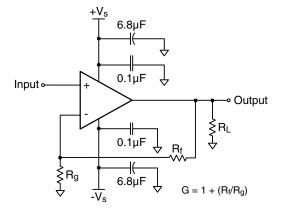


Figure 1: Typical Non-Inverting Gain Circuit

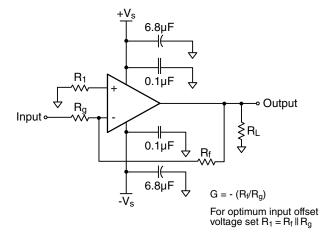


Figure 2: Typical Inverting Gain Circuit

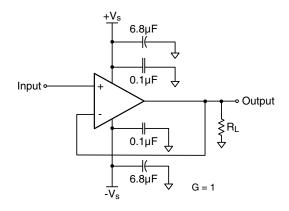


Figure 3: Unity Gain Circuit

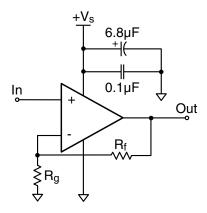


Figure 4: Single Supply Non-Inverting Gain Circuit

At non-inverting gains other than G = +1, keep R_g below $1k\Omega$ to minimize peaking; thus for optimum response at a gain of +2, a feedback resistor of $1k\Omega$ is recommended. Figure 5 illustrates the CLC1005, CLC1015 and CLC2005 frequency response with both $1k\Omega$ and $2k\Omega$ feedback resistors.

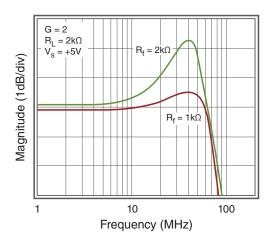


Figure 5: Frequency Response vs. Rf

Overdrive Recovery

For an amplifier, an overdrive condition occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the ranges are exceeded. The CLC1005, CLC1015, and CLC2005 will typically recover in less than 20ns from an overdrive condition. Figure 6 shows the CLC2005 in an overdriven condition.

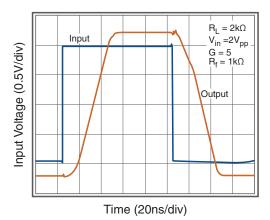


Figure 6: Overdrive Recovery

Enable/Disable Function

The CLC1015 offers an active-low disable pin that can be used to lower its supply current. Leave the pin floating to enable to part. Pull the disable pin to the negative supply (which is ground in a single supply application) to disable the output. During the disable condition, the nominal supply current will drop below $127\mu A$ and the output will be at a high impedance with about 2pF capacitance.

Power Dissipation

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Power dissipation should not be a factor when operating under the stated $2k\Omega$ load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond it's intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Theta $_{JA}$ (θ_{JA}) is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} + (\theta_{JA} \times P_D)$$

Where $T_{\mbox{\sc Ambient}}$ is the temperature of the working environment.

In order to determine PD, the power dissipated in the load

needs to be subtracted from the total power delivered by the supplies.

Supply power is calculated by the standard power equation.

$$P_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMSsupply}}$$

$$V_{\text{supply}} = V_{\text{S+}} - V_{\text{S-}}$$

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{load})_{RMS^2})/Rload_{eff}$$

The effective load resistor (Rload_{eff}) will need to include the effect of the feedback network. For instance,

Rloadeff in Figure 3 would be calculated as:

$$R_L \parallel (R_f + R_g)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here, P_D can be found from

Quiescent power can be derived from the specified I_S values along with known supply voltage, V_{supply} . Load power can be calculated as above with the desired signal amplitudes using:

$$(V_{load})_{RMS} = V_{peak} / \sqrt{2}$$

 $(I_{load})_{RMS} = (V_{load})_{RMS} / Rload_{eff}$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{Dvnamic} = (V_{S+} - V_{load})_{RMS} \times (I_{load})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or $V_{\text{supply}}/2$.

The CLC1015 is short circuit protected. However, this may not guarantee that the maximum junction temperature (+150°C) is not exceeded under all conditions. Figure 7 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

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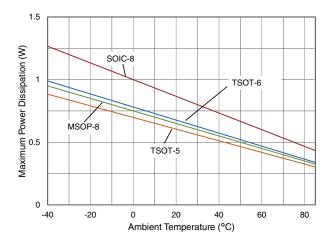


Figure 7. Maximum Power Derating

Driving Capacitive Loads

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance, R_S , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 8.

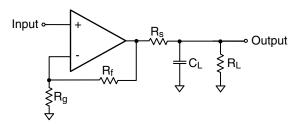


Figure 8. Addition of R_S for Driving Capacitive Loads

Table 1 provides the recommended R_S for various capacitive loads. The recommended R_S values result in approximately <1dB peaking in the frequency response.

C _L (pF)	R _S (Ω)	-3dB BW (MHz)
22pF	0	118
47pF	15	112
100pF	15	91
492pF	6.5	59

Table 1: Recommended R_S vs. C_I

For a given load capacitance, adjust R_S to optimize the tradeoff between settling time and bandwidth. In general, reducing R_S will increase bandwidth at the expense of additional overshoot and ringing.

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Exar has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8µF and 0.1µF ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board #	Products
CEB002	CLC1005 and CLC1015 in TSOT
CEB003	CLC1005 in SOIC
CEB006	CLC2005 in SOIC
CEB010	CLC2005 in MSOP

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 9-18. These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

- 1. Short -V_S to ground.
- Use C3 and C4, if the -V_S pin of the amplifier is not directly connected to the ground plane.

exar.com/CLC1005

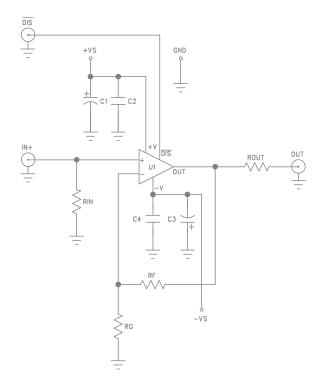


Figure 9. CEB002 and CEB003 Schematic

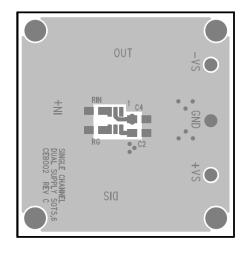


Figure 10. CEB002 Top View

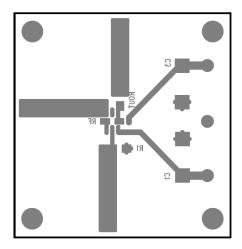


Figure 11. CEB002 Bottom View

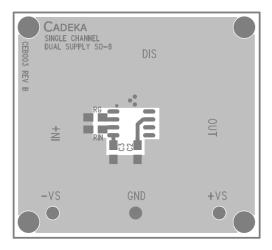


Figure 12. CEB003 Top View

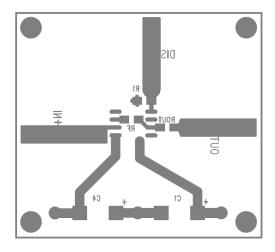


Figure 13. CEB003 Bottom View

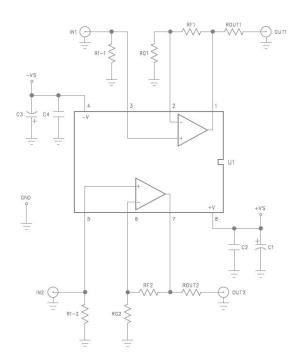


Figure 14. CEB006 & CEB010 Schematic

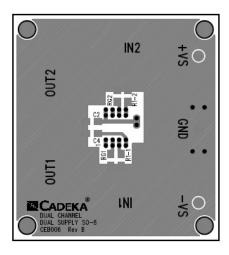


Figure 15. CEB006 Top View

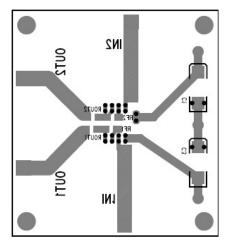


Figure 16. CEB006 Bottom View

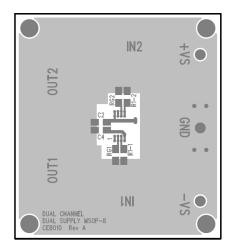


Figure 17. CEB010 Top View

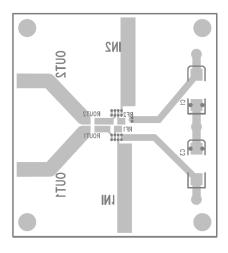
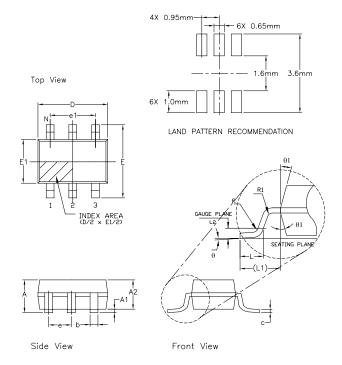


Figure 18. CEB010 Bottom View

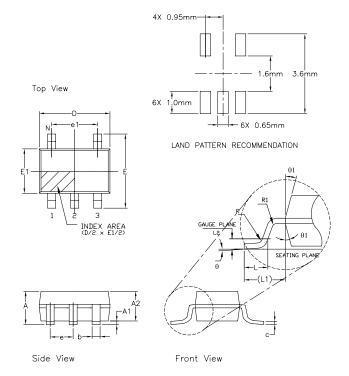
Mechanical Dimensions

TSOT-6 Package



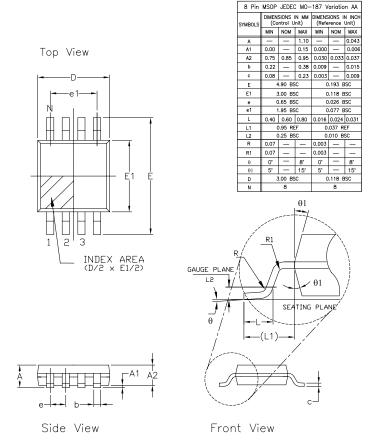
6 PIN TSOT (OPTION 2)						
SYMBOLS	DIMENSION IN MM (Control Unit)			DIMENSION IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.75	_	0.80	0.030	_	0.031
A1	0.00		0.05	0.000	_	0.002
A2	0.70	0.75	0.78	0.028	0.036	0.031
Ь	0.35	_	0.50	0.012	_	0.020
С	0.10		0.20	0.003	_	0.008
D	2.90 BSC			0.114 BSC		
Е	2.80 BSC			0.110 BSC		
E1	1.60 BSC			0.063 BSC		
е	0.95 BSC			0.038 BSC		
e1	1.90 BSC			0.075 BSC		
L	0.37	0.45	0.60	0.012	0.018	0.024
L1	0.60 REF			0.	.024 RE	F
L2	0.25 BSC			0.010 BSC		iC
R	0.10	_	_	0.004	_	_
R1	0.10	_	0.25	0.004	_	0.010
θ	0,	4*	8*	0,	4*	8*
θ1	4*	10*	12*	4°	10°	12°
N	6				6	

TSOT-5 Package

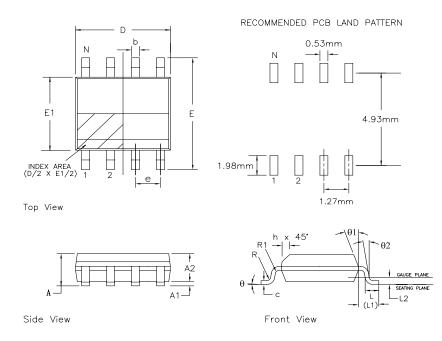


5 Pin TSOT (OPTION 2)						
SYMBOLS	DIMENSION IN MM (Control Unit)			DIMENSION IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.75	_	0.80	0.030	_	0.031
A1	0.00	_	0.05	0.000	_	0.002
A2	0.70	0.75	0.78	0.028	0.030	0.031
b	0.35	_	0.50	0.012	_	0.020
С	0.10	_	0.20	0.003	_	0.008
D	2.90 BSC			0.114 BSC		
E	2.80 BSC			0.110 BSC		
E1	1.60 BSC			0.063 BSC		
е	0.95 BSC			0.038 BSC		
e1	1.90 BSC			0.075 BSC		
L	0.37	0.45	0.60	0.012	0.018	0.024
L1	0.60 REF			0	.024 RE	F
L2	0.25 BSC			0	.010 BS	iC .
R	0.10	_	_	0.004	_	_
R1	0.10	_	0.25	0.004	_	0.010
θ	0,	4*	8,	0,	4.	8*
θ1	4.	10°	12*	4.	10°	12*
N	5				5	

MSOP-8 Package



SOIC-8 Package



8 Pin	SOICN	JEDE	EC MS-	-012 '	Variatio	n AA
SYMBOLS	DIMENSIONS IN MM (Control Unit)				SIONS IN erence Ur	
	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.35	_	1.75	0.053	_	0.069
A1	0.10	_	0.25	0.004	_	0.010
A2	1.25	_	1.65	0.049	_	0.065
b	0.31	_	0.51	0.012	_	0.020
С	0.17	_	0.25	0.007	_	0.010
E	6.00 BSC			0.236 BSC		
E1	3.90 BSC			0.154 BSC		
е	1.27 BSC			0.050 BSC		
h	0.25	_	0.50	0.010	_	0.020
L	0.40	_	1.27	0.016	_	0.050
L1	1.04 REF			0.041 REF		
L2	0.25 BSC			0.010 BSC		
R	0.07	_	_	0.003	_	_
R1	0.07	_	_	0.003	_	-
θ	0,	_	8°	0,	_	8.
θ1	5°		15°	5°		15°
θ2	0,	_		0°	_	_
D	4.90 BSC			0.193 BSC		
N	8				8	

Ordering Information

Part Number	Package	Green	Operating Temperature Range	Packaging		
CLC1005 Ordering Information	CLC1005 Ordering Information					
CLC1005IST5X	TSOT-5	Yes	-40°C to +85°C	Tape & Reel		
CLC1005IST5MTR	TSOT-5	Yes	-40°C to +85°C	Mini Tape & Reel		
CLC1005IST5EVB	Evaluation Board	N/A	N/A	N/A		
CLC1005ISO8X	SOIC-8	Yes	-40°C to +85°C	Tape & Reel		
CLC1005ISO8MTR	SOIC-8	Yes	-40°C to +85°C	Mini Tape & Reel		
CLC1005ISO8EVB	Evaluation Board	N/A	N/A	N/A		
CLC1015 Ordering Information						
CLC1015IST6X	TSOT-6	Yes	-40°C to +85°C	Tape & Reel		
CLC1015IST6MTR	TSOT-6	Yes	-40°C to +85°C	Mini Tape & Reel		
CLC1015IST6EVB	Evaluation Board	N/A	N/A	N/A		
CLC2005 Ordering Information						
CLC2005ISO8X	SOIC-8	Yes	-40°C to +85°C	Tape & Reel		
CLC2005ISO8MTR	SOIC-8	Yes	-40°C to +85°C	Mini Tape & Reel		
CLC2005ISO8EVB	Evaluation Board	N/A	N/A	N/A		
CLC2005IMP8X	MSOP-8	Yes	-40°C to +85°C	Tape & Reel		
CLC2005IMP8MTR	MSOP-8	Yes	-40°C to +85°C	Mini Tape & Reel		
CLC2005IMP8EVB	Evaluation Board	N/A	N/A	N/A		

Moisture sensitivity level for all parts is MSL-1. Mini tape and reel quantity is 250.

Revision History

Revision	Date	Description
2D (ECN 1513-01)	March 2015	Reformat into Exar data sheet template. Updated ordering information table to include MTR and EVB part numbers. Updated thermal resistance numbers and package outline drawings. Added CLC1015 back into data sheet.

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